

RoHS

COMPLIANT

HALOGEN FREE

Available

Vishay Siliconix

N-Channel Reduced Q_g , Fast Switching MOSFET

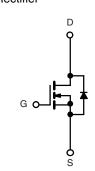
PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
30	0.008 at V _{GS} = 10 V	16			
	0.011 at V _{GS} = 4.5 V	15			

FEATURES

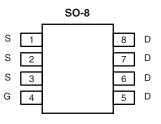
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET[®] Power MOSFETs
- PWM Optimized for High Efficiency
- 100 % R_g Tested ٠

APPLICATIONS

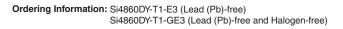
- Buck Converter
 - High Side
 - Low Side
- Synchronous Rectifier - Secondary Rectifier



N-Channel MOSFET



Top View



ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise n	oted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage		V _{GS}	± 20			
	T _A = 25 °C	- I _D	16	11	•	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		13	8		
Pulsed Drain Current		I _{DM}	± 50		A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	3.0	1.40		
Mariana Diata india	T _A = 25 °C	P _D	3.5	1.6	W	
Maximum Power Dissipation ^a	T _A = 70 °C		2.2	1.0		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lumation to Ambient (MOCEET)	t ≤ 10 s	- R _{thJA}	29	35	°C/W
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State		67	80	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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MOSFET SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1.0			V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1			
		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			5	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	40			А		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 16 A		0.0066	0.008	0		
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 15 \text{ A}$		0.0090	0.011	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 16 A		60		S		
Diode Forward Voltage ^a	V _{SD}	$I_{S} = 3 \text{ A}, V_{GS} = 0 \text{ V}$		0.70	1.1	V		
Dynamic ^b								
Total Gate Charge	Qg			13	18			
Gate-Source Charge	Q _{gs}	V_{DS} = 15 V, V_{GS} = 4.5 V, I_{D} = 16 A		5		nC		
Gate-Drain Charge	Q _{gd}			4.0		1		
Gate Resistance	Rg		1.0	1.7	2.9	Ω		
Turn-On Delay Time	t _{d(on)}			18	27			
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		12	18			
Turn-Off Delay Time	t _{d(off)}	$\rm I_D \cong 1$ A, $\rm V_{GEN}$ = 10 V, $\rm R_g$ = 6 Ω		46	70	ns		
Fall Time	t _f			19	30			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 3 A, dI/dt = 100 A/μs		40	70			

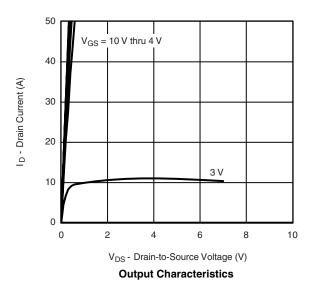
Notes:

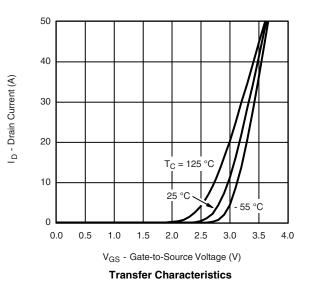
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





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Si4860DY

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Ciss

12

25

4

50

75

Capacitance

18

24

100

 $I_{D} = 16 \text{ Å}$

8

10

6

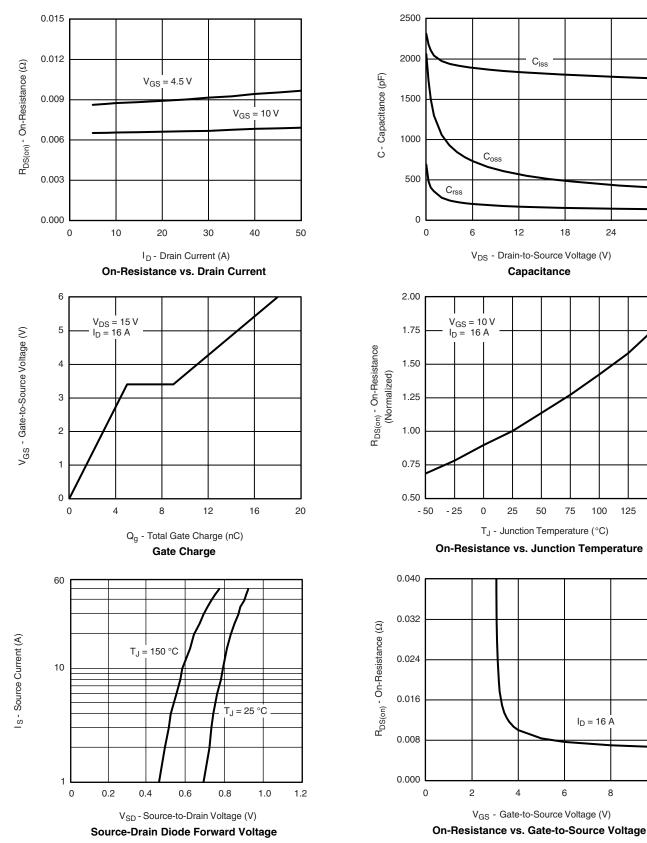
125

150

30

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VISHAY

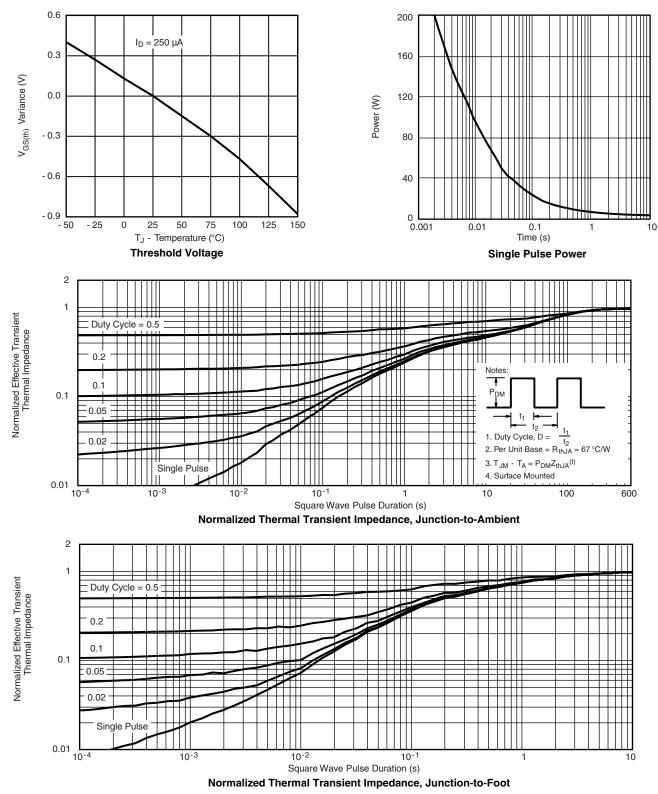


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Si4860DY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?71752</u>.

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